

Technical Data
Data Sheet 3170, Rev. A

403CMQ080/403CMQ100 SCHOTTKY RECTIFIER

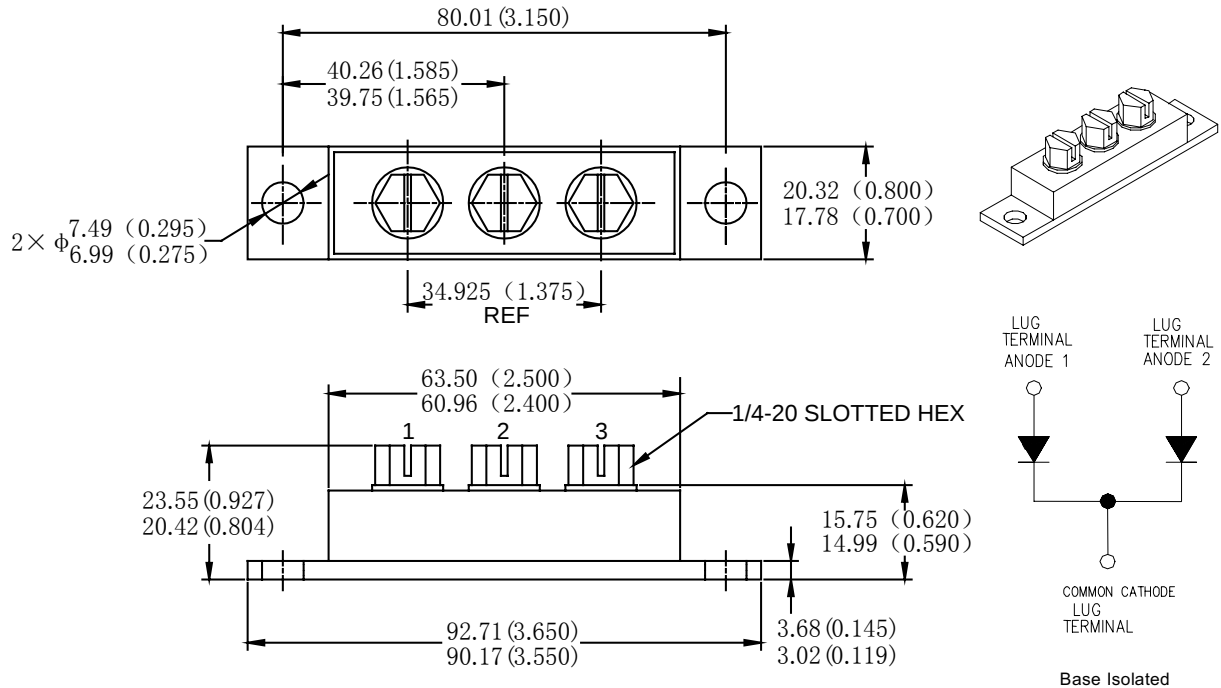
Applications:

- High current switching power supply • Plating power supply • Free-Wheeling diodes
- Reverse battery protection • Converters • UPS System • Welding

Features:

- 175 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Mechanical Dimensions: In Inches / mm



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2
Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80(403CMQ080) 100(403CMQ100)	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 85^\circ\text{C}$, rectangular wave form	200 400	per leg per device A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	3960	A
Non-Repetitive Avalanche Energy (per leg)	E_{AS}	$T_J = 25^\circ\text{C}$, $I_{AS} = 1\text{ A}$, $L = 30\text{ mH}$	15	mJ
Repetitive Avalanche Current (per leg)	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical	1	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 200 A, Pulse, $T_J = 25^\circ\text{C}$ @ 400 A, Pulse, $T_J = 25^\circ\text{C}$	0.83 0.97	V
	V_{F2}	@ 200 A, Pulse, $T_J = 125^\circ\text{C}$ @ 400 A, Pulse, $T_J = 125^\circ\text{C}$	0.69 0.82	V
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R = \text{rated } V_R$, $T_J = 25^\circ\text{C}$	6	mA
	I_{R2}	@ $V_R = \text{rated } V_R$, $T_J = 125^\circ\text{C}$	140	mA
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{ V}$, $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{ MHz}$	5500	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μs

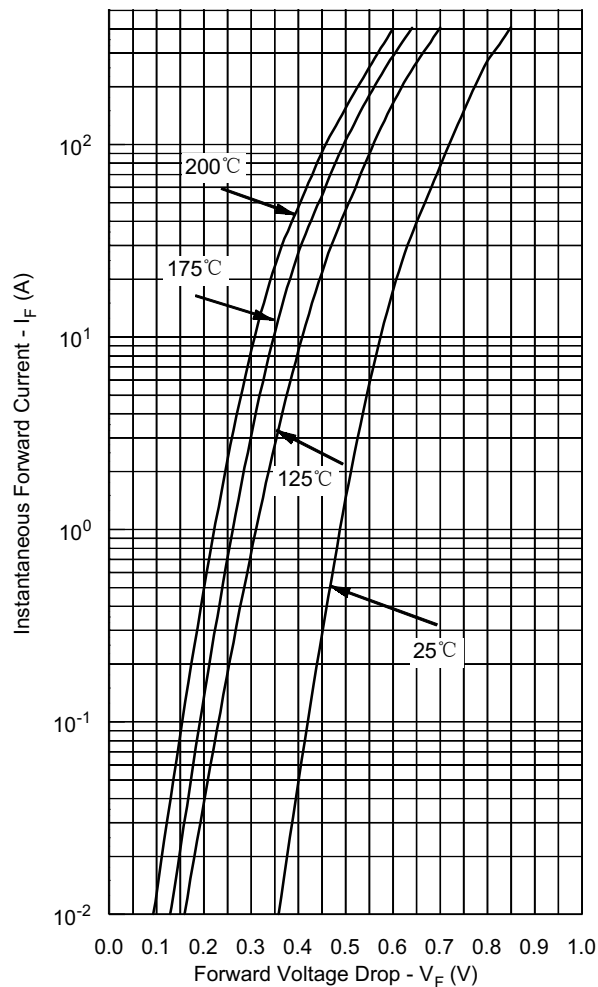
* Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications:

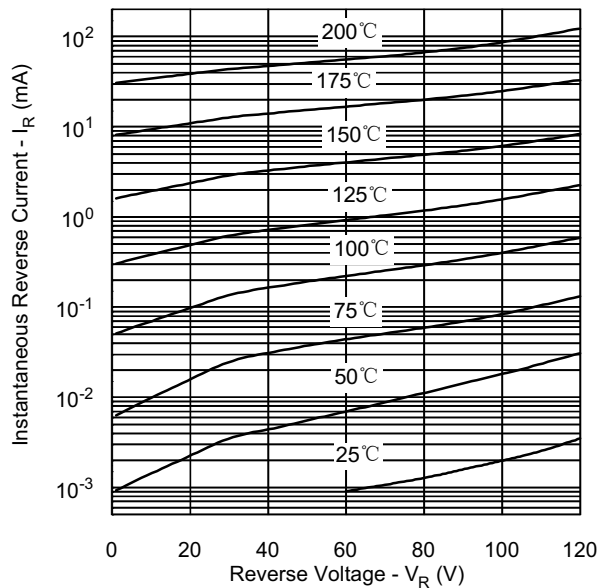
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	$^\circ\text{C}$
Max. Storage Temperature	T_{stg}	-	-55 to +175	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	0.40	$^\circ\text{C/W}$
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	0.20	$^\circ\text{C/W}$
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.10	$^\circ\text{C/W}$
Approximate Weight	wt	-	79	g
Mounting Torque	T_M	-	Mounting Torque Base Terminal Torque	24 (min) 35 (max) 35 (min) 46 (max) Kg-cm
Case Style	PRM4 Isolated			

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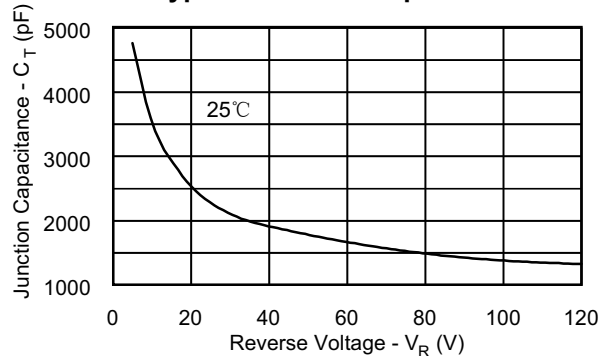
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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